

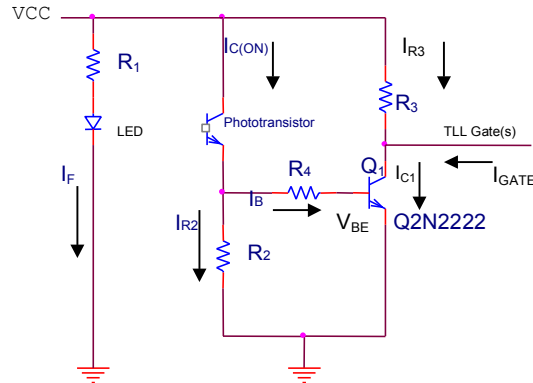
# TTL Interface Circuit for Optoelectronic Devices

## Application Bulletin 234



Typical TTL interfacing requires 1.6mA sinking current ( $I_{GATE}$ ) with a maximum voltage of 0.4V at the input of the TTL gate. Some optoelectronics components are not capable of sinking 1.6mA of Collector Current ( $I_{C(ON)}$ ), hence additional circuitry is needed to achieve the interface requirements. The transistor buffer, Figure 1, is a cost effective choice to interface circuits with TTL devices. If designed properly, the circuit can provide optimum noise immunity and fast switching.

The selection of  $R_3$  depends on the gain ( $\beta$ ) of  $Q_1$  and  $I_{C(ON)}$  from the optoelectronic device:  $R_3$  should be chosen for the lowest possible value.



The Equations for the above circuit:

$$I_{R3} = \frac{(V_{CC} - V_{CE(Q1)})}{R_3} \quad (1.1)$$

$$I_{C1} = (I_{R3} + I_{GATE}) \quad (1.2)$$

$$I_B = \frac{(I_{C1})}{\beta} \quad (1.3)$$

$$I_{R2} = (I_{C(ON)} - I_B) \quad (1.4)$$

$$R_2 = \frac{(V_{BE} + I_B R_4)}{I_{R2}} \quad (1.5)$$

$R_1$  is the current limiting resistor for the Infrared LED.

$$R_1 = \frac{(V_{CC} - V_{F(LED)})}{I_F} \quad (1.6)$$

### General Note

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Example using the above equations:

A phototransistor with an  $I_{C(ON)min} = 500\mu A$

Q1 parameters:

2N2222 ( $\beta = \square 60$  min)  $V_{CC} = 5 V$ .

Typically  $R_3 = 1k\Omega$  □ resistor is used as a pull-up resistor for TTL interface.

From (1.1):

$$I_{R3} = \frac{(5 - 0.4)}{1000} = 4.6mA$$

To support TTL interface, the circuit needs to be able to sink  $1.6mA = I_{GATE}$ .

From (1.2)

$$I_{C1} = (4.6mA - (-1.6mA)) = 6.2mA$$

From (1.3)

$$I_B = \frac{(6.2mA)}{60} = 103\mu A$$

To choose the  $R_2$  value:

$$I_{R2} = (500\mu A - 103\mu A) = 397\mu A$$

Typically  $R_4 = 1k\Omega$  □ □ base current limiting resistor for TTL interface.

From (1.5):

$$R_2 = \frac{(0.7V + 103\mu A \times 1k\Omega)}{397\mu A} \cong 2.02k\Omega$$

Complete saturation of the phototransistor is not necessary, however, adjustment to  $R_2$  may be required if sensor is too sensitive. For example: if sensor is affected by ambient light lower the  $R_2$  value.

To calculate the current limiting resistor for the LED use (1.6)

Desired  $I_F = 20mA$ .

$$R_1 = \frac{(5 - 1.3(\text{typical}))}{20mA} = 185\Omega$$

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